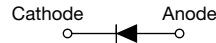


Hyperfast Rectifier, 1 A FRED Pt[®]


SMA (DO-214AC)


FEATURES

- Hyperfast recovery time, reduced Q_{rr} , and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
 COMPLIANT
 HALOGEN
FREE

LINKS TO ADDITIONAL RESOURCES



3D Models


 Application
 Notes

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	1 A
V_R	1200 V
V_F at I_F	1.33 V
t_{rr}	45 ns
T_J max.	175 °C
Package	SMA (DO-214AC)
Circuit configuration	Single

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use as clamp, snubber and freewheeling diode in a flyback aux power supplies, bootstrap and desaturate for HV MOSFET and IGBT driver, high frequency rectifiers in a cuk and sepic circuit for LED lighting.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

MECHANICAL DATA

Case: SMA (DO-214AC)

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V_{RRM}		1200	V
Average rectified forward current	$I_{F(AV)}$	$T_{SP} = 142\text{ °C}$, $D = 0.5$	1	A
Non-repetitive peak surge current	I_{FSM}	$T_J = 25\text{ °C}$, 8.3 ms sine pulse	21	
Operating junction and storage temperatures	T_J , T_{Stg}		-55 to +175	°C



ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	1200	-	-	V
Forward voltage drop	V _F	I _F = 1 A	-	1.75	2.25	
		I _F = 1 A, T _J = 125 °C	-	1.40	1.65	
Reverse leakage current	I _R	V _R = V _R rated	-	-	5	μA
		T _J = 150 °C, V _R = V _R rated	-	-	50	
Junction capacitance	C _T	V _R = 1200 V, 1 MHz	-	3.5	-	pF

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t _{rr}	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A	-	35	45	ns
		T _J = 25 °C	-	90	-	
		T _J = 125 °C	-	110	-	
Peak recovery current	I _{RRM}	T _J = 25 °C	-	3	-	A
		T _J = 125 °C	-	4	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C	-	95	-	nC
		T _J = 125 °C	-	190	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction to mount	R _{thJM} ⁽¹⁾	Device mounted on PCB with 2 x 3.5 mm soldering lands	-	15	18	°C/W
Thermal resistance, junction to ambient	R _{thJA}	Device mounted on PCB with recommended pad size	-	110	-	°C/W
Approximate weight			0.07			g
Marking device		Case style SMA (DO-214AC)	1X12			

Note

(1) Thermal resistance junction to mount follows JEDEC® 51-14 transient dual interface test method (TDIM)

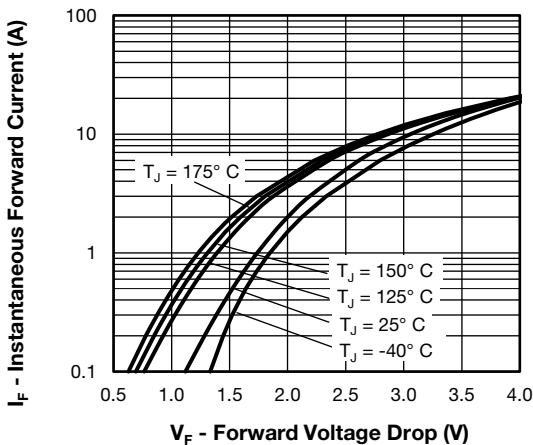


Fig. 1 - Typical Forward Voltage Drop Characteristics

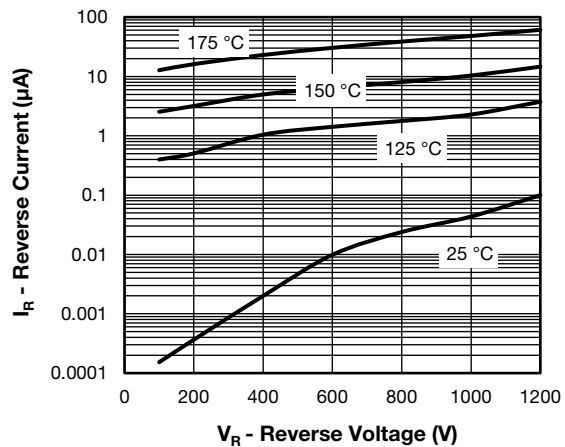


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

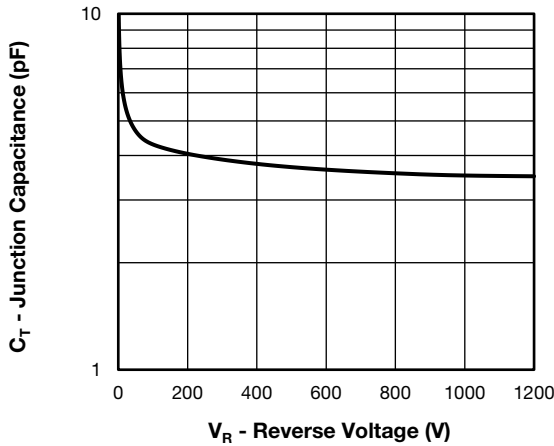


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

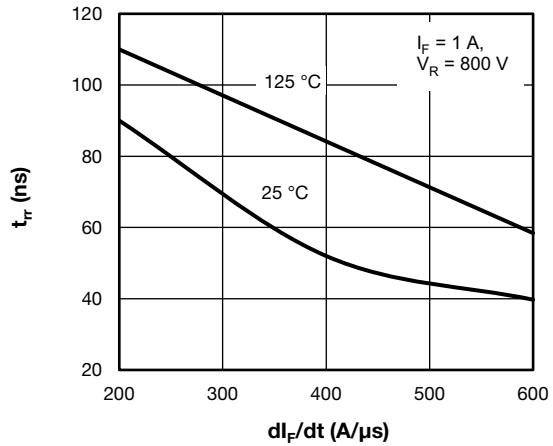


Fig. 6 - Typical Reverse Recovery Time vs. dI_F/dt

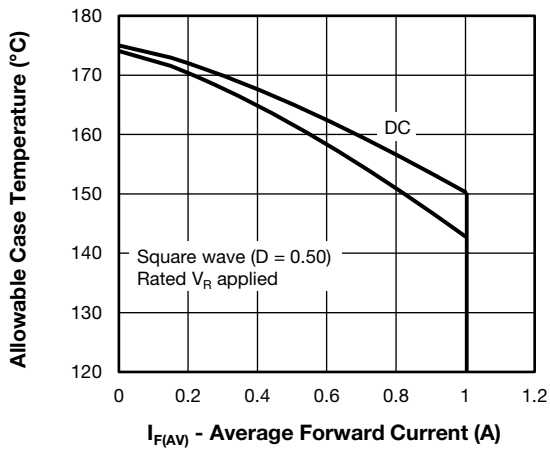


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

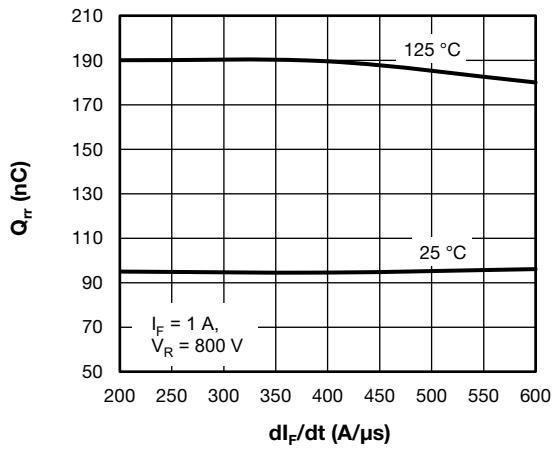


Fig. 7 - I_{rr} (A) vs. dI_F/dt

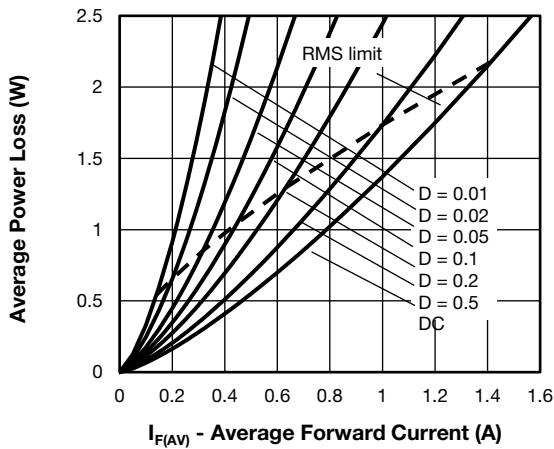


Fig. 5 - Forward Power Loss Characteristics

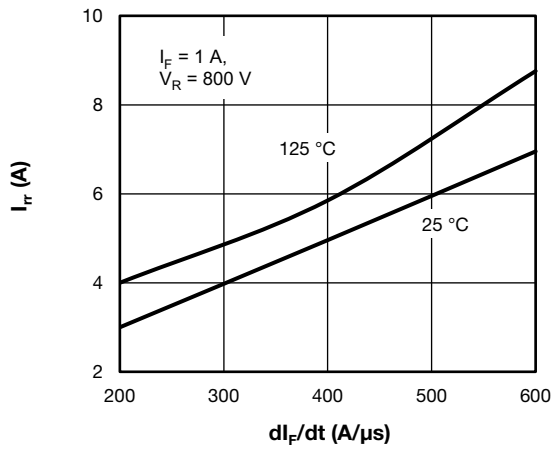


Fig. 8 - Typical Stored Charge vs. dI_F/dt

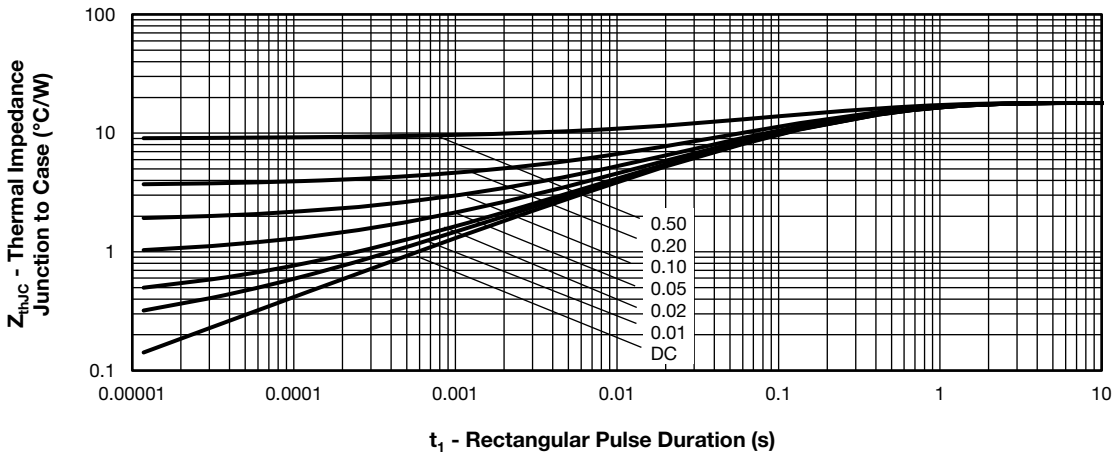


Fig. 9 - Transient Thermal Impedance, Junction to Case

ORDERING INFORMATION TABLE

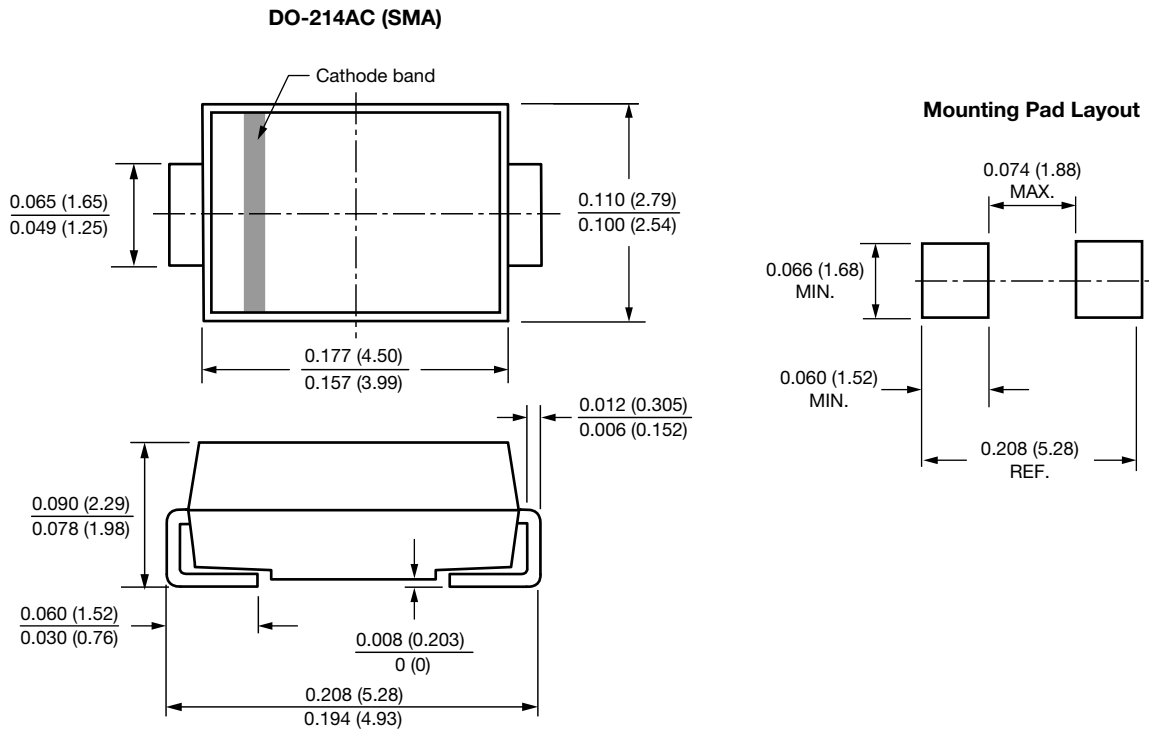
Device code	VS-	E	7	M	X	01	12	-M3	
	①	②	③	④	⑤	⑥	⑦	⑧	
	1	-	Vishay Semiconductors product	2	-	Circuit configuration: E = single diode	3	-	7 = FRED generation 7
	4	-	M = SMA package	5	-	Process type, X = hyperfast recovery	6	-	Current rating (01 = 1 A)
	7	-	Voltage code (12 = 1200 V)	8	-	-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free			

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER REEL	BASE QUANTITY	PACKAGING DESCRIPTION
VS-E7MX0112-M3/I	7500	7500	13" diameter plastic tape and reel

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95400
Part marking information	www.vishay.com/doc?95472
Packaging information	www.vishay.com/doc?95404

SMA

DIMENSIONS in inches (millimeters)





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